

### **Description**

The 74LVC1G32 is a single 2-input positive OR gate with a standard push-pull output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output preventing damaging current backflow when the device is powered down.

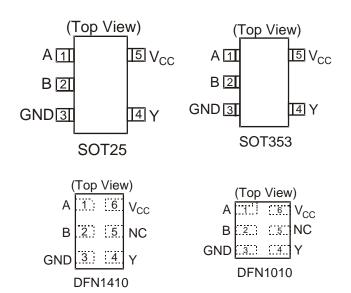
The gate performs the positive Boolean function:

$$Y = A + B$$
 or  $Y = \overline{A \bullet B}$ 

#### **Features**

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- I<sub>OFF</sub> Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - o Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- · Range of Package Options
- Direct Interface with TTL Levels
- All packages Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

#### **Pin Assignments**



### **Applications**

- Voltage Level Shifting
- General Purpose Logic
- Bus Driver / Repeater
- Power Down Signal Isolation
- General Purpose Logic
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Tablet Computers, E-readers
  - Computer peripherals, hard drives, CD/DVD ROM
  - o TV, DVD, DVR, set top box
  - Cell Phones, Personal Navigation / GPS
  - o MP3 players ,Cameras, Video Recorders

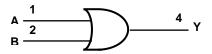
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.



## **Pin Descriptions**

Pin Name	Description
Α	Data Input
В	Data Input
GND	Ground
Υ	Data Output
V <sub>CC</sub>	Supply Voltage
NC	No Connection

## **Logic Diagram**



### **Function Table**

Inp	Output	
Α	В	Y
Н	X	Н
X	Н	Н
Ĺ	L	L

### **Absolute Maximum Ratings (Note 2)**

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
$V_{CC}$	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I <sub>OFF</sub> state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state.	-0.3 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> <0	-50	mA
l <sub>OK</sub>	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
I <sub>CC,</sub> I <sub>GND</sub>	Continuous current through V <sub>CC</sub> or GND	±100	mA
$T_J$	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



## **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit
V	On anoting a Valtage	Operating	1.65	5.5	V
V <sub>CC</sub>	Operating Voltage	Data retention only	1.5		V
		V <sub>CC</sub> = 1.65V to 1.95V	0.65 X V <sub>CC</sub>		
\ /	High lovel land Maltage	$V_{CC} = 2.3V$ to 2.7V	1.7		V
$V_{IH}$	High-level Input Voltage	V <sub>CC</sub> = 3V to 3.6V	2		V
		V <sub>CC</sub> = 4.5V to 5.5V	0.7 X V <sub>CC</sub>		
		V <sub>CC</sub> = 1.65V to 1.95V		0.35 X V <sub>CC</sub>	
	Low-level input voltage	V <sub>CC</sub> = 2.3V to 2.7V		0.7	
$V_{IL}$		V <sub>CC</sub> = 3V to 3.6V		0.8	V
		V <sub>CC</sub> = 4.5V to 5.5V		0.3 X V <sub>CC</sub>	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
	V <sub>CC</sub> = 1.65V		-4		
	High-level output current	$V_{CC} = 2.3V$		-8	
$I_{OH}$		V 2V		-16	mA
		$V_{CC} = 3V$		-24	
		$V_{CC} = 4.5V$		-32	
		V <sub>CC</sub> = 1.65V		4	
		$V_{CC} = 2.3V$		8	
$I_{OL}$	Low-level output current	$V_{CC} = 3V$		16	mA
		VCC = 3V		24	
		$V_{CC} = 4.5V$		32	
	Innut transition visa == f=11	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20	
$\Delta t/\Delta V$	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		10	ns/V
Tale	$V_{CC} = 5V \pm 0.5V$		5		
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at  $V_{\mbox{CC}}$  or Ground.



# Electrical Characteristics (All typical values are at $V_{CC} = 3.3V$ , $T_A = 25$ °C)

Cumbal	Downwoodon	Took Conditions	Test Conditions V-			-40°C to 85°C			I Init
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Min	Max	Unit
		I <sub>OH</sub> = -100μA	1.65V to 5.5V	V <sub>CC</sub> – 0.1			V <sub>CC</sub> – 0.1		
		I <sub>OH</sub> = -4mA	1.65V	1.2			0.95		
V	High Level	$I_{OH} = -8mA$	2.3V	1.9			1.7		V
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -16mA	3V	2.4			2.2		V
	Vollago	I <sub>OH</sub> = -24mA	3٧	2.3			2.0		
		$I_{OH} = -32mA$	4.5V	3.8			3.4		
		I <sub>OL</sub> = 100μA	1.65V to 5.5V			0.1		0.1	
		I <sub>OL</sub> = 4mA	1.65V			0.45		0.7	
\ \/	V <sub>OL</sub> Cow Level Output Voltage	I <sub>OL</sub> = 8mA	2.3V			0.3		0.45	V
VOL		I <sub>OL</sub> = 16mA	3V			0.4		0.6	
		I <sub>OL</sub> = 24mA				0.55		0.8	
		$I_{OL} = 32mA$	4.5V			0.55		.8	
I <sub>I</sub>	Input Current	V <sub>I</sub> = 5.5 V or GND	0 to 5.5V		± 0.1	±5		± 100	μΑ
I <sub>OFF</sub>	Power Down Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 5.5V	0V			±10		±200	μΑ
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> =0	5.5V		0.1	10		200	μΑ
ΔI <sub>CC</sub>	Additional Supply Current	One input at V <sub>CC</sub> – 0.6V Other inputs at V <sub>CC</sub> or GND	3V to 5.5V			500		5000	μΑ
C <sub>i</sub>	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3V		5				pF



## Package Characteristics (All typical values are at Vcc = 3.3V, T<sub>A</sub> = 25°C)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Unit
		SOT25			204		
	Thermal Resistance	SOT353	(Nata 4)		371		°C/W
$\theta_{JA}$	Junction-to-Ambient	DFN1010	(Note 4)		445		
		DFN1410			460		
	Thermal Resistance Junction-to-Case	SOT25	(Note 4)		52		°C/W
		SOT35			143		
$\theta_{\text{JC}}$		DFN1010			250		
		DFN1410			265		

Notes: 4. Test condition for SOT25, SOT353, DFN1410 and DFN1010: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

## **Switching Characteristics**

Figure 1 Typical Values at  $T_A = 25$  °C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

Parameter	From	То	V <sub>CC</sub>	T <sub>A</sub>	= -40°C to 8	5ºC	$T_A = -40^{\circ}$	C to 125°C	Unit
raiailletei	Input	Output	<b>V</b> CC	Min	Тур.	Max	Min	Max	Oilit
			$1.8V \pm 0.15V$	1.0	3.1	8.0	1.0	10.5	
			$2.5V \pm 0.2V$	0.5	2.1	5.5	0.5	7.0	
t <sub>pd</sub>	A or B	Υ	2.7V	0.5	2.5	5.5	0.5	7.0	ns
			$3.3V \pm 0.3V$	0.5	2.1	4.5	0.5	6.0	
			$5.0V \pm 0.5V$	0.5	1.7	4.0	0.5	5.5	

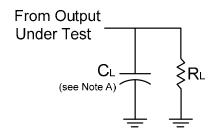
## **Operating Characteristics**

 $T_A = 25 \, {}^{\circ}C$ 

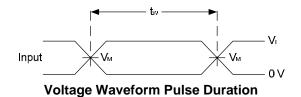
Parameter		Test Conditions	V <sub>CC</sub> = 1.8V Typ.	V <sub>CC</sub> = 2.5V Typ.	V <sub>CC</sub> = 3.3V Typ.	V <sub>CC</sub> = 5V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	20	20	21	22	pF

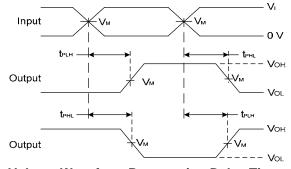


#### **Parameter Measurement Information**



V	Inputs		V	•	В
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL	$R_L$
1.8V ± 0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30 pF	1 ΚΩ
2.5V ± 0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30 pF	500 Ω
2.7V	V <sub>CC</sub>	≤2.5ns	1.5V	50 pF	500 Ω
$3.3V \pm 0.3V$	3.0 V	≤2.5ns	1.5V	50 pF	500 Ω
$5.0V \pm 0.5V$	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	50 pF	500 Ω





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD.</sub>



### **Ordering Information**

 74LVC1G 32 XXX - 7

 Logic Device
 Function
 Package
 Packing

 74 : Logic Prefix
 32 : 2-Input
 W5 : SOT25
 7 : Tape & Reel

 LVC : 1.65 to 5.5V
 OR-Gate
 SE : SOT353

Family FW4 : DFN1010 1G : One gate FZ4 : DFN1410

Davisa	Package	Packaging	7" Tape a	and Reel
Device	Code	(Note 6)	Quantity	Part Number Suffix
74LVC1G32W5-7	W5	SOT25	3000/Tape & Reel	-7
74LVC1G32SE-7	SE	SOT353	3000/Tape & Reel	-7
74LVC1G32FW4-7	FW4	DFN1010	5000/Tape & Reel	-7
74LVC1G32FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

Notes:

- Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

### **Marking Information**

#### (1) SOT25 and SOT353

Part Number	Package	Identification Code
74LVC1G32W5	SOT25	UW
74LVC1G32SE	SOT353	UW

#### (2) ) DFN1010 and DFN1410

(Top View) \_\_

XX : Identification Code Y : Year 0~9



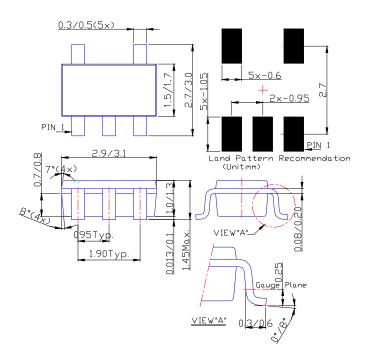
\overline{\text{W}} : Week : A-Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week \overline{\text{X}} : A-Z : Internal Code

Part Number	Package	Identification Code	
74LVC1G32FW4	DFN1010	UW	
74LVC1G32FZ4	DFN1410	UW	

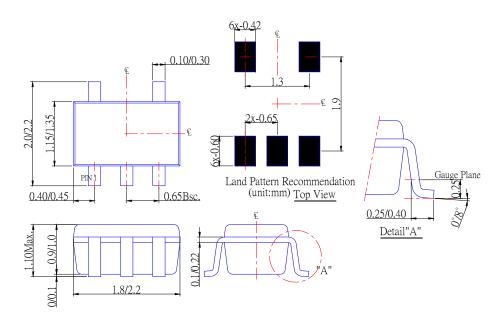


### Package Outline Dimensions (All Dimensions in mm)

#### (1) Package Type: SOT25



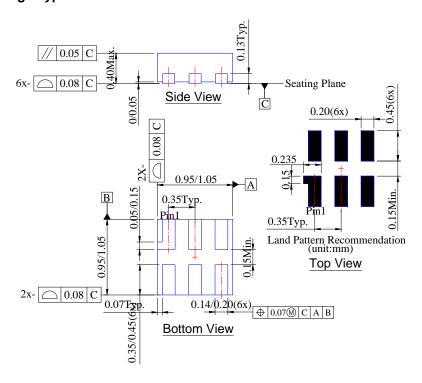
#### (2) Package Type: SOT353



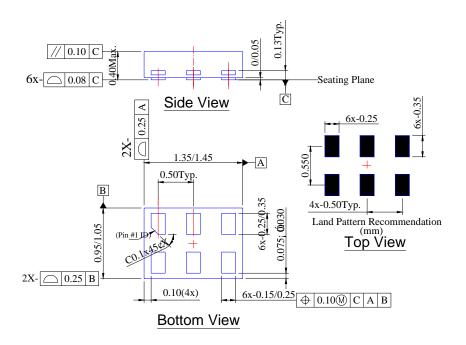


#### Package Outline Dimensions (cont.)

#### (3) Package Type DFN1010



#### (4) Package Type: DFN1410





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